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[4856]-23

F.E. (Second Semester) EXAMINATION, 2015

APPLIED SCIENCE

Paper II

(Physics)

(2008 PATTERN)

Time : Two Hours

Maximum Marks : 50

N.B. :— (i) Neat diagrams must be drawn wherever necessary.

(ii) Figures to the right indicate full marks.

(iii) Assume suitable data, if necessary.

(iv) Use of logarithmic tables slide rule, Mollier charts, electronic pocket calculator and steam tables is allowed.

Constants :

Charge on electron $e = 1.6 \times 10^{-19}$ C

Mass of electron $m = 9.1 \times 10^{-31}$ kg

Planck's const. $h = 6.63 \times 10^{-34}$ J.s.

1. (a) State Heisenberg's Uncertainty principle. Illustrate it with electron diffraction due to single slit. [6]
- (b) Derive Schrödinger's time independent wave equation. Also write the Schrödinger's time dependent wave equation. [7]
- (c) An electron is trapped in a rigid box of width 2Å . Find its lowest three permissible energies in eV. [4]

P.T.O.

Or

2. (a) State de Broglie's hypothesis. Derive the equation for de Broglie wavelength in terms of energy and potential difference 'V'. [6]
- (b) Derive the expression for energy and wavefunction of a particle trapped in an infinite potential well. Give the graphical representation for ψ and $|\psi|^2$. [7]
- (c) An electron is accelerated through a potential difference of 10 kV. Calculate the de Broglie wavelength and momentum of the electron. [4]
3. (a) Explain the construction and working of Ruby laser with neat and labelled diagrams. [7]
- (b) Distinguish between Type I and Type II superconductors. [6]
- (c) Define : [4]
- (1) Spontaneous emission
 - (2) Stimulated emission
 - (3) Population inversion
 - (4) Pumping.

Or

4. (a) Explain the construction and working of He-Ne laser with neat and labelled diagrams. [7]

- (b) Explain the terms : [6]
- (1) Meissner effect
 - (2) Critical magnetic field.
- (c) What do you mean by Holography ? Explain the process of construction of Hologram with neat and labelled diagram. [4]
- 5.** (a) Using the Fermi-Dirac probability distribution function, show that the Fermi-level in the intrinsic semiconductor lies at the centre of the band gap. [6]
- (b) Explain the optical and electrical properties of nanoparticles. [6]
- (c) Calculate the number of acceptors to be added to germanium sample to obtain the resistivity of $10 \Omega\text{-cm}$.
Given : $\mu = 1700 \text{ cm}^2/\text{Volt-sec}$. [4]
- Or*
- 6.** (a) Explain the working of P-N junction diode on the basis of energy band diagrams for : [6]
- (1) Forward bias
 - (2) Reverse bias.
- (b) Explain the construction and working of solar cell. Also draw the I-V characteristics of solar cell. [6]
- (c) Explain the synthesis of metal nano-particles by colloidal route. [4]